

	Type	Hits	Search Text	DBs	Time Stamp
1	IS&R	69	("438/722").CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/02/15 13:22
2	BRS	69	((("438/722").CCLS.) and @ad<=20010613	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/02/14 13:26
3	BRS	223162	438/\$.ccls. or 257/\$.ccls. and @ad<=20010113	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/02/15 10:38
4	BRS	35716	(438/\$.ccls. or 257/\$.ccls. and @ad<=20010113) and 'dielectric'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/02/14 14:15
5	BRS	4864	((438/\$.ccls. or 257/\$.ccls. and @ad<=20010113) and 'dielectric') and 'mosfet'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/02/14 14:12
6	BRS	1	((438/\$.ccls. or 257/\$.ccls. and @ad<=20010113) and 'dielectric') and 'mosfet') and 'group IV metal'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/02/14 14:14
7	BRS	16571	(438/\$.ccls. or 257/\$.ccls. and @ad<=20010113) and 'dielectric layer'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/02/14 14:21
8	BRS	61	((438/\$.ccls. or 257/\$.ccls. and @ad<=20010113) and 'dielectric layer') and 'hafnium' and 'lanthanum'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/02/14 14:25
9	BRS	104	((438/\$.ccls. or 257/\$.ccls. and @ad<=20010113) and 'dielectric') and 'hafnium' and 'lanthanum'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/02/14 14:25
10	BRS	36	((438/\$.ccls. or 257/\$.ccls. and @ad<=20010113) and 'dielectric') and 'amorphous oxide'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/02/14 14:26
11	BRS	1	((438/\$.ccls. or 257/\$.ccls. and @ad<=20010113) and 'dielectric') and 'hafnium' and 'lanthanum' and 'amorphous oxides'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/02/14 14:26
12	BRS	224025	438/\$.ccls. or 257/\$.ccls. and @ad<=20010613	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/02/15 10:55
13	BRS	15	(438/\$.ccls. or 257/\$.ccls. and @ad<=20010613) and 'mosfet' and 'dielectric metal oxide'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/02/15 10:49
14	BRS	4906	(438/\$.ccls. or 257/\$.ccls. and @ad<=20010613) and 'mosfet' and 'dielectric'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/02/15 10:51
15	BRS	73	((438/\$.ccls. or 257/\$.ccls. and @ad<=20010613) and 'mosfet' and 'dielectric') and 'hafnium'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/02/15 10:53
16	BRS	24	((438/\$.ccls. or 257/\$.ccls. and @ad<=20010613) and 'mosfet' and 'dielectric') and 'hafnium') and 'lanthanum'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/02/15 10:55
17	IS&R	2	("6020024").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/02/15 11:22
18	IS&R	4	("4432035").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/02/15 13:44
19	IS&R	417	("257/411").CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/02/15 16:09
20	BRS	5	((("257/411").CCLS.) and 'hafnium' and 'lanthanum'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/02/15 13:46